

# 1 Channel Compact High Side Switch ICs

# Automotive 1ch Adjustable Current Limit High Side Switch ICs

# BD22441G-C

### **General Description**

BD22441G-C is low on-resistance N-channel MOSFET high-side power switch, optimized for Universal Serial Bus (USB) applications. BD22441G-C is equipped with the function of over-current detection, thermal shutdown, under-voltage lockout and soft-start. Moreover, the range of Current limit threshold can be adjusted from 0.2A to 1.7A by changing the external resistance.

# **Key Specifications**

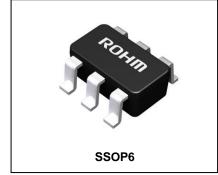
IN Operating Voltage: 2.8V to 5.5V
 On Resistance: (VIN=5V) 100mΩ(Typ)
 Current Limit Threshold: 0.2A to 1.7A adjustable
 Standby Current: 0.01μA (Typ)
 Operating Temperature Range: -40°C to +125°C

#### **Features**

- AEC-Q100 Qualified<sup>(Note 1)</sup>
- Adjustable Current Limit Threshold: 0.2A to 1.7A
- Built-in Low On-Resistance (Typ 100mΩ) N-channel MOSFET Built-in
- Soft-Start Circuit
- Output Discharge Function
- Open-Drain Fault Flag Output
- Thermal Shutdown
- Under-Voltage Lockout
- Reverse Current Protection when Power Switch Off (Note 1: Grade1)

#### Package SSOP6

W(Typ) x D(Typ) x H(Max) 2.90mm x 2.80mm x 1.25mm



### **Applications**

Car accessory

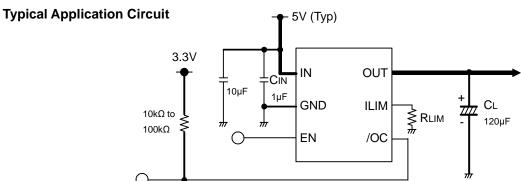


Figure 1. Typical Application Circuit

# **Block Diagram**

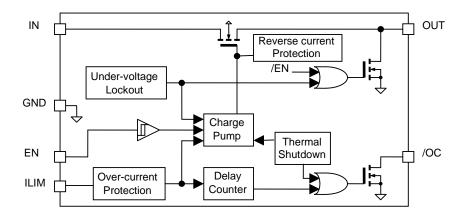


Figure 2. Block Diagram

# **Pin Configuration**

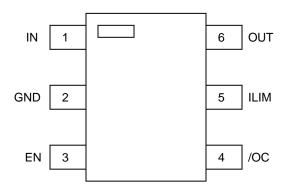


Figure 3. Pin Configuration (TOP VIEW)

### **Pin Descriptions**

Docor iptioi	occirpations							
Pin No.	Symbol	I/O	Function					
1	IN	I	Switch input and the supply voltage for the IC.					
2	GND	-	Ground.					
3	EN	I	Enable input. High-level input turns on the switch.					
4	/OC	0	Over-current detection terminal.  Low level output during over-current or over-temperature condition.  Open-drain fault flag output.					
5	ILIM	0	Current limit threshold set Pin. External resistor used to set Current limit threshold. Recommended 11.97 k $\Omega$ $\leq$ R <sub>LIM</sub> $\leq$ 106.3 k $\Omega$					
6	OUT	0	Power switch output.					

**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Rating	Unit
IN Supply Voltage	VIN	-0.3 to +7.0	V
EN Input Voltage	V <sub>EN</sub>	-0.3 to +7.0	V
ILIM Voltage	VILIM	-0.3 to +7.0	V
ILIM Source Current	IILIM	1	mA
/OC Voltage	V/oc	-0.3 to +7.0	V
/OC Sink Current	I/oc	10	mA
OUT Voltage	V <sub>OUT</sub>	-0.3 to +7.0	V
Storage Temperature	Tstg	-55 to +150	°C
Power Dissipation	Pd	0.67 <sup>(Note1)</sup>	W

(Note 1) Mounted on 70mm x 70mm x 1.6mm glass epoxy board. Reduce 5.4mW per 1°C above 25°C

Caution1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with power dissipation taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

**Recommended Operating Conditions** 

Parameter	Cymbol		Lloit		
Farameter	Symbol	Min	Тур	Max	Unit
IN Operating Voltage	Vin	2.8	5.0	5.5	V
Operating Temperature	Topr	-40	-	+125	°C

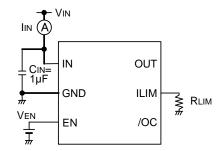
### Electrical Characteristics ( $V_{IN} = 5V$ , $R_{LIM} = 20k\Omega$ , $-40^{\circ}C \le Tj \le +125^{\circ}C$ , unless otherwise specified.) <u>DC Characteristics</u>

Parameter	Symbol	Limit		Unit	Conditions	
		Min	Тур	Max		
Operating Current	I <sub>DD</sub>	-	120	220	μA	V <sub>EN</sub> = 5V, V <sub>OUT</sub> = open
Standby Current	Istb	-	0.01	10	μA	V <sub>EN</sub> = 0V, V <sub>OUT</sub> = open
EN Input Voltage	V <sub>ENH</sub>	2.7	-	-	V	High input
EN Input Voltage	V <sub>ENL</sub>	-	-	0.7	V	Low input
EN Input Leakage	I <sub>EN</sub>	-1	0.01	1	μA	V <sub>EN</sub> = 0V or 5V
On-Resistance	Ron	-	100	280	mΩ	Iоит = 500mA
Reverse Leak Current	I <sub>REV</sub>	-	-	10	μA	Vout = 5V, VIN = 0V
		122	212	330	mA	$R_{LIM} = 100k\Omega$
Current Limit Threshold	I <sub>TH</sub>	822	1028	1234		$R_{LIM} = 20k\Omega$
		1405	1696	1987		$R_{LIM} = 12k\Omega$
Output Discharge Resistance	Rdisc	-	60	180	Ω	I <sub>OUT</sub> = 1mA, V <sub>EN</sub> = 0V
/OC Output Low Voltage	V/oc	-	-	0.4	V	I/oc = 1mA
LIV/I O Throshold	V <sub>TUVH</sub>	2.30	2.55	2.80	V	V <sub>IN</sub> increasing
UVLO Threshold	V <sub>TUVL</sub>	2.25	2.50	2.75	V	V <sub>IN</sub> decreasing

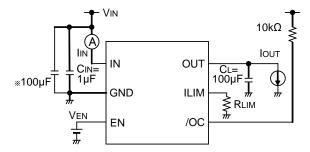
# **AC Characteristics**

Davamatar	Coursels al	Limit		l lmit	O and distinguish		
Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
Output Rise Time	t <sub>ON1</sub>	-	0.6	6	ms		
Output Turn-On Time	ton2	-	1	10	ms	R <sub>L</sub> = 100Ω	
Output Fall Time	toff1	-	1.8	20	μs	RL = 10022	
Output Turn-Off Time	toff2	-	3.2	40	μs		
/OC Delay Time	t/oc	4	7	12	ms		

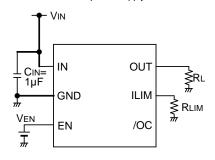
### **Measurement Circuit**



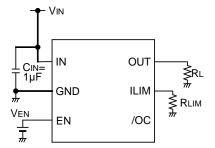
A. Operating Current, Standby Current



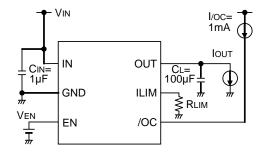
C. On-Resistance, Current Limit Threshold, /OC Delay Time \*\*Use capacitance more than 100µF at output short circuit test by using external power supply.



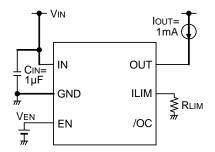
E. UVLO Threshold



B. EN Input Voltage, Output Rise/Fall Time Output Turn-On/ Turn-Off Time



D. /OC Output Low Voltage



F. Output Discharge Resistance

Figure 4. Measurement Circuit

# **Timing Diagram**

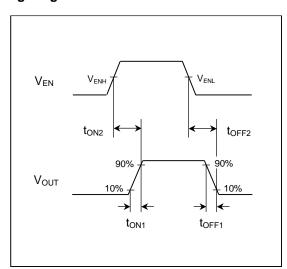


Figure 5. Output Rise/Fall Time

# **Typical Performance Curves**

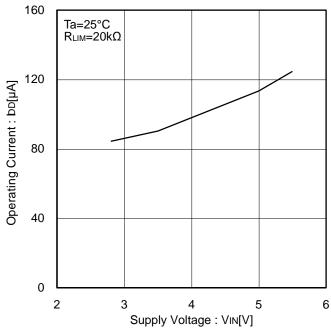


Figure 6. Operating Current vs Supply Voltage (EN Enable)

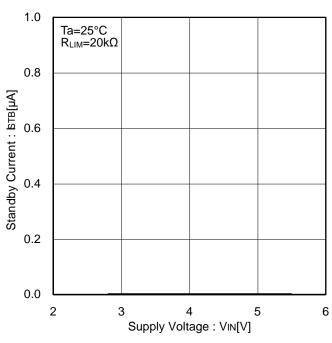


Figure 8. Standby Current vs Supply Voltage (EN Disenable)

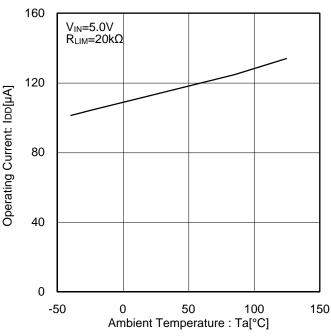


Figure 7. Operating Current vs Ambient Temperature (EN Enable)

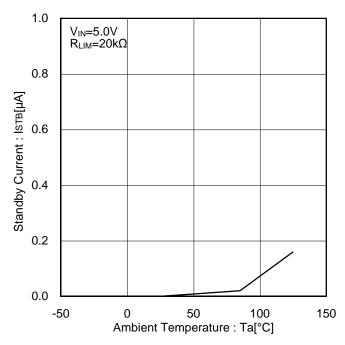
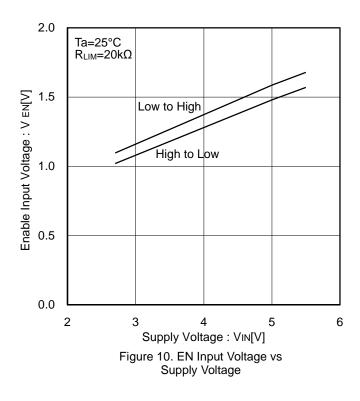
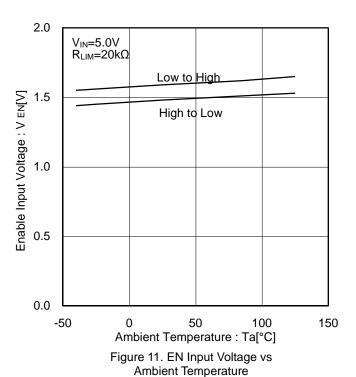
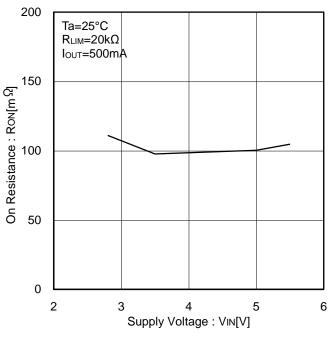


Figure 9. Standby Current vs Ambient Temperature (EN Disenable)







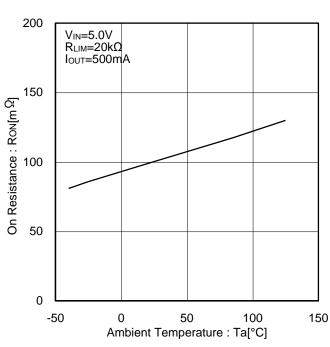
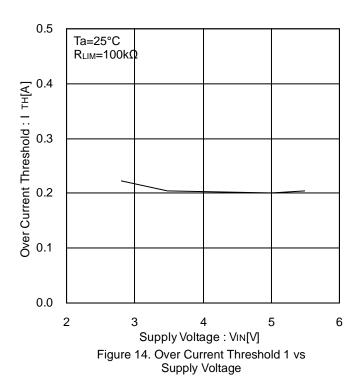


Figure 12. On-Resistance vs Supply Voltage

Figure 13. On-Resistance vs Ambient Temperature

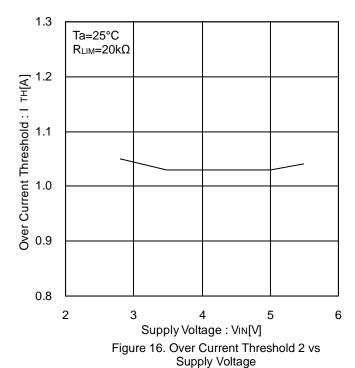


0.5 V<sub>IN=5.0V</sub> R<sub>LIM</sub>=100kΩ

0.4 V<sub>IN=100kΩ</sub>

0.3 0.1 0.2 0.1 0.2 0.1 0.2 0.1 0.1 150 Ambient Temperature : Ta[°C]

Figure 15. Over Current Threshold 1 vs Ambient Temperature



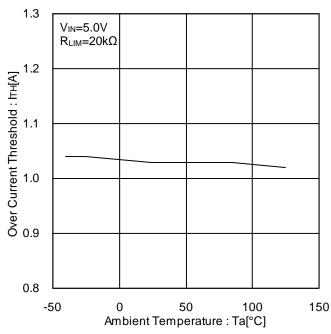
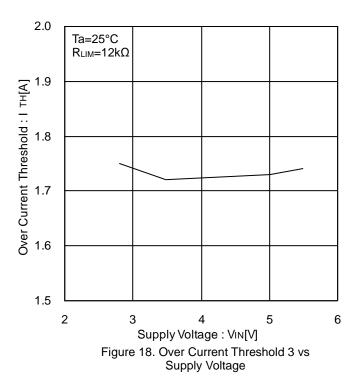


Figure 17. Over Current Threshold 2 vs Ambient Temperature



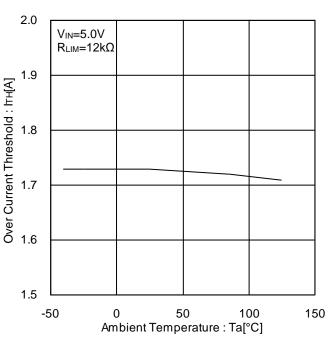
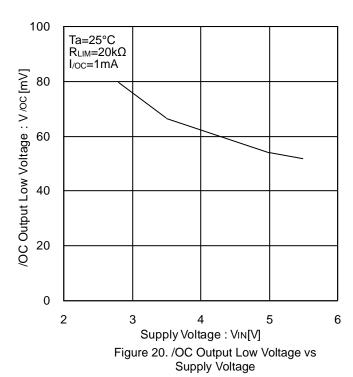


Figure 19. Over Current Threshold 3 vs Ambient Temperature



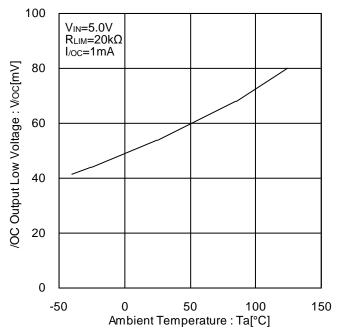
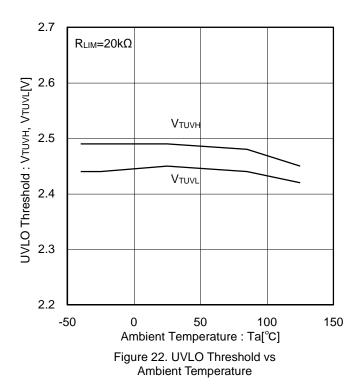


Figure 21. /OC Output Low Voltage vs Ambient Temperature



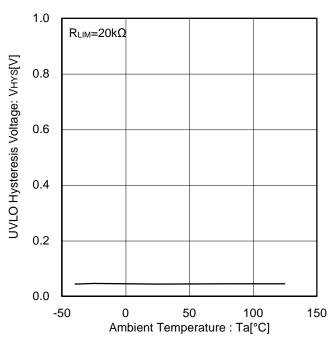
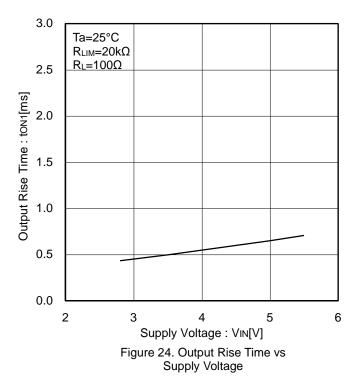
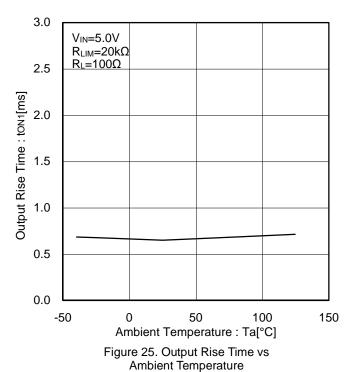
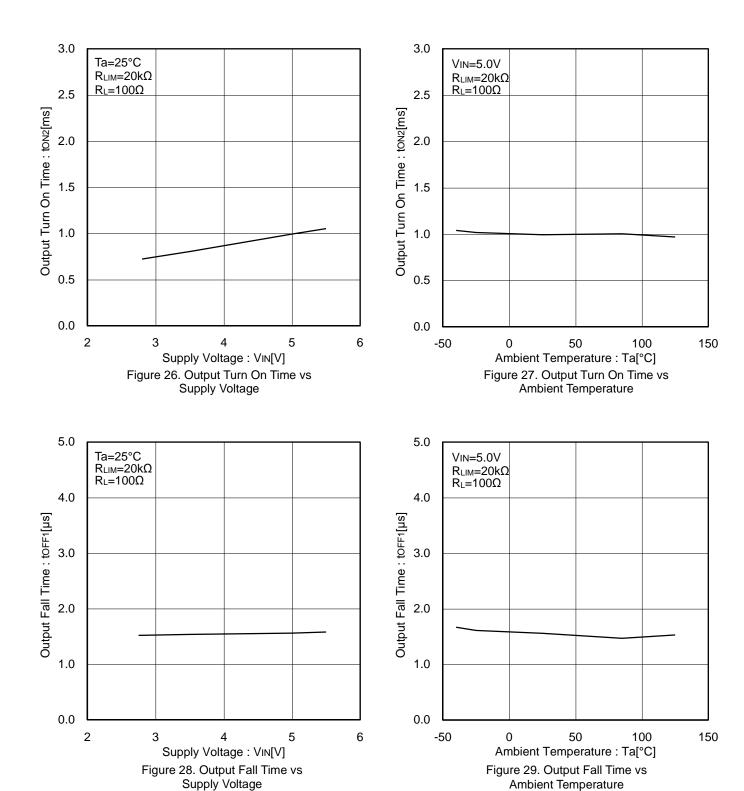
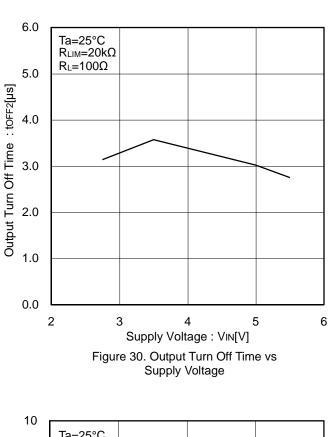


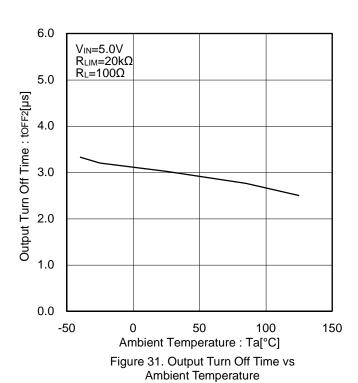
Figure 23. UVLO Hysteresis Voltage vs Ambient Temperature









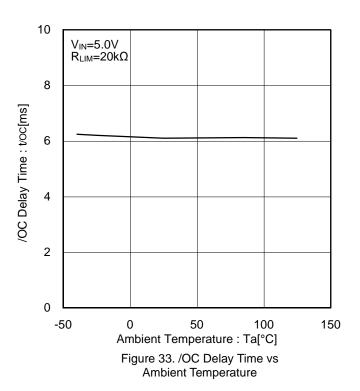


Ta=25°C
R<sub>LIM</sub>=20kΩ

8

Supply Voltage: VIN[V]
Figure 32. /OC Delay Time vs

Supply Voltage



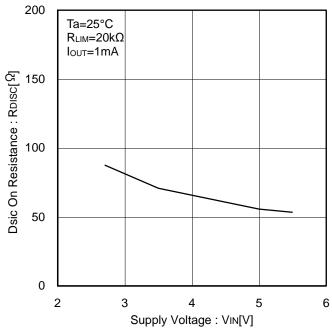


Figure 34. Discharge On Resistance vs Supply Voltage

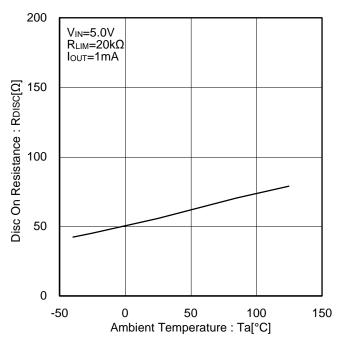
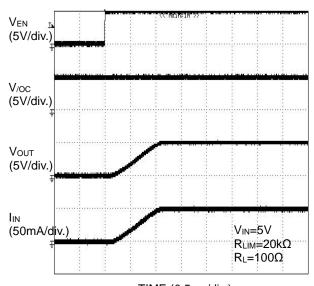
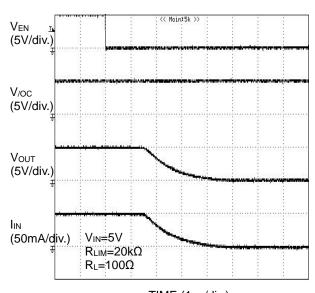


Figure 35. Discharge On Resistance vs Ambient Temperature

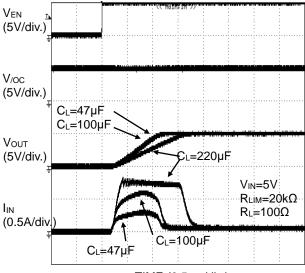
# **Typical Wave Forms**



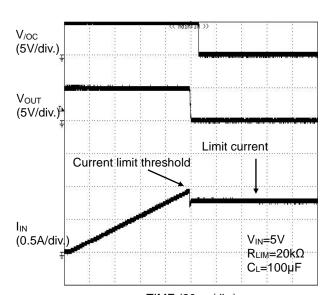
TIME (0.5ms/div.) Figure 36. Output Rise Characteristic



TIME (1µs/div.)
Figure 37. Output Fall Characteristic

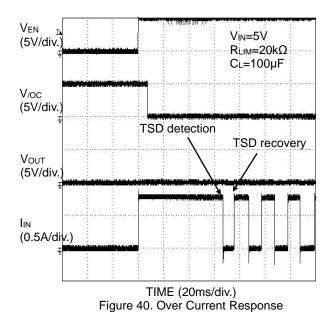


TIME (0.5ms/div.) Figure 38. Inrush Current Response

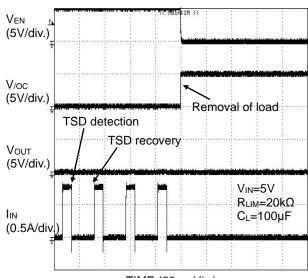


TIME (20ms/div.) Figure 39. Over Current Response Ramped Load

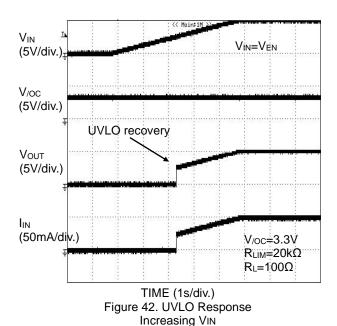
# **Typical Wave Forms - continued**



Enable Into Short Circuit



TIME (20ms/div.)
Figure 41. Over Current Response
Disenable From Short Circuit



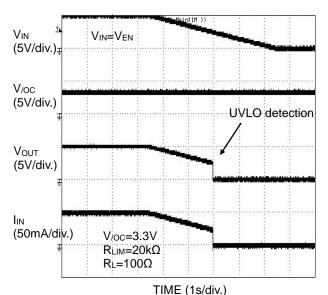


Figure 43. UVLO Response Decreasing VIN

# Typical Wave Forms - continued

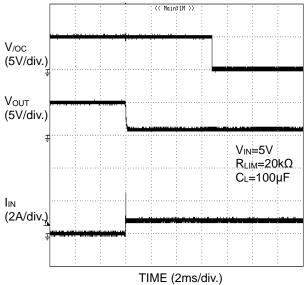
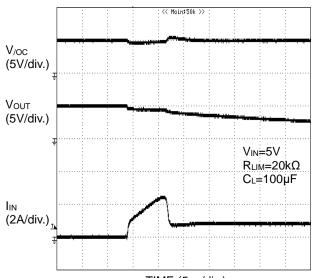
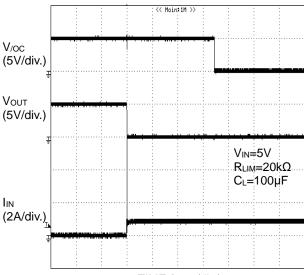


Figure 44. Over Current Response 1Ω Load Connected At Enable



TIME (5 $\mu$ s/div.) Figure 45. Over Current Response  $1\Omega$  Load Connected At Enable



TIME (2ms/div.)
Figure 46. Over Current Response
0Ω Load Connected At Enable

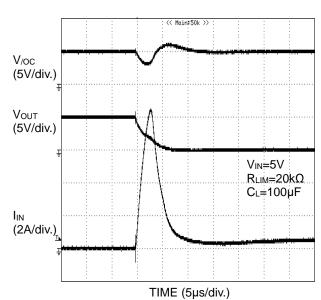


Figure 47. Over Current Response 0Ω Load Connected At Enable

### **Application Circuit Example**

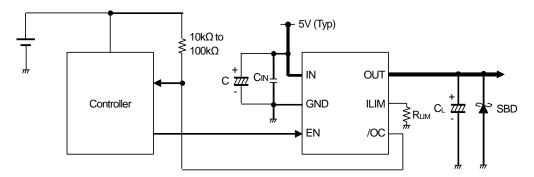


Figure 48. Application Circuit Example

### **Application Information**

Ringing may cause bad influences on IC operations. In order to avoid this case, connect a low ESR bypass capacitor across IN terminal and GND terminal of IC.  $1\mu F$  or higher is recommended. When excessive current flows due to output short-circuit or so, ringing occurs because of inductance between power source line to IC may exert a bad influence upon IC. In order to decrease voltage fluctuations from power source line to IC, connect a low ESR capacitor in parallel with CIN.  $10\mu F$  to  $100\mu F$  or higher is effective.

When OUT terminal voltage is less than the absolute voltage (-0.3V), there is possibility that this IC suffers physical damage by parasitic diode. Recommended Voltage is over -0.3V. When OUT terminal and GND terminal short-circuit, undershoot occurs. To reduce undershoot level, recommendation is to put CL and SBD near the OUT terminal. As pattern-layout and Application affect the undershoot level, make sure to leave an adequate margin. Pull up /OC output via resistance value of  $10k\Omega$  to  $100k\Omega$ .

When using the circuit with changes to the external circuit constants, make sure to leave an adequate margin for external components including AC/DC characteristics as well as the dispersion of the IC.

### **Functional Description**

#### 1. Switch Operation

IN terminal and OUT terminal are connected to the drain and the source of switch MOSFET respectively. The IN terminal is also used as power source input to internal control circuit.

When the switch is turned on from EN control input, the IN and OUT terminals are connected by a  $100m\Omega(Typ)$  switch. In ON status, the switch is bidirectional. Therefore, when the potential of OUT terminal is higher than that of the IN terminal, current flows from OUT terminal to IN terminal.

Since a parasitic diode between the drain and the source of switch MOSFET is canceled, current flow from OUT to IN is prevented during off state.

### 2. Thermal Shutdown Circuit (TSD)

If over-current limit would continue, the temperature of the IC would increase drastically. If the junction temperature goes beyond 120°C (Typ) in the condition of over-current detection, thermal shutdown circuit operates and turns power switch off, causing the IC to output a fault flag (/OC). Then, when the junction temperature decreases lower than 110°C(Typ), the power switch is turned on and fault flag (/OC) is cancelled. Also, regardless of over-current condition, if the junction temperature were beyond 160°C (Typ), thermal shutdown circuit makes power switch turn off and outputs fault flag (/OC). When junction temperature decreases lower than 140°C (Typ), power switch is turned on and fault flag (/OC) is cancelled. This operation repeats, unless the increase of chip's temperature is removed or the output of power switch is turned OFF. Fault flag (/OC) is output without delay time at thermal shutdown. The thermal shutdown circuit operates when the switch is ON (EN signal is active).

### 3. Over-Current Detection (OCD)

The over-current detection circuit limits current ( $I_{SC}$ ) and outputs error flag (/OC) when current flowing in each switch MOSFET exceeds a specified value. The over-current detection circuit works when the switch is on (EN signal is active). There are three types of response against over-current.

- (1) When the switch is turned on while the output is in short circuit status, the switch gets into current limit status immediately. (See figure 40.)
- (2) When the output short-circuits or high capacity load is connected while the switch is on, very large current flows until the over-current limit circuit reacts. When the over-current detection and limit circuit operates, current limitation is carried out.(See figure 46,47.)
- (3) When the output current increases gradually, current limitation would not operate unless the output current exceeds the over-current detection value. When it exceeds the over-current detection value, current limitation is carried out. (See Figure 39.)

### 4. Under-Voltage Lockout (UVLO)

UVLO circuit prevents the switch from turning on until the  $V_{IN}$  exceeds 2.55V(Typ). If the  $V_{IN}$  drops below 2.5V(Typ) while the switch turns on, then UVLO shuts off the power switch. UVLO has hysteresis of 50mV(Typ). Under-voltage lockout circuit operates when the switch is on (EN signal is active). (see Figure 42,43.)

### 5. Fault Flag (/OC) Output

Fault flag output is an N-MOS open drain output. At detection of over-current or thermal shutdown, output is low-level. Over-current detection has delay filter. This delay filter prevents instantaneous current detection such as inrush current at switch on, hot plug from being informed to outside, but if charge up time for output capacitance is longer than delay time, fault flag output asserts low level. When output current is close to Current Limit Threshold value, fault flag output (/OC) might be low level before turning to over-current condition because it is affected by current swinging or noise. If fault flag(/OC) output is unused, /OC pin should be connected to open or ground line.

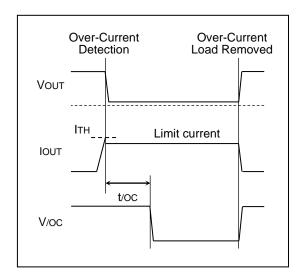


Figure 49. Over-Current Detection

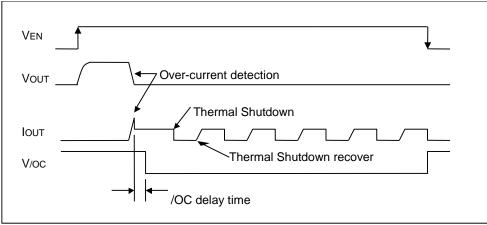


Figure 50. Over-Current Detection, Thermal Shutdown Timing

### 6. Adjustable Current Limit Threshold

BD22441G-C is able to change over-current detection value from 0.2A(Typ) to 1.7A(Typ) by connecting resistance (R<sub>LIM</sub>) between ILIM pin and GND pin. The resistance value from  $11.97K\Omega$  to  $106.3k\Omega$  is recommended for R<sub>LIM</sub>. The relational expression and the table for resistance value and over-current detection value are described below. Allocate R<sub>LIM</sub> close to IC as possible. Be careful not to be affected by parasitic resistance of board pattern because over-current detection value is depended on the resistance value between ILIM pin and GND pin. ILIM pin cannot be used as open and short to GND pin. The R<sub>LIM</sub> resistance tolerance directly affects the current limit threshold accuracy. Recommended to use low tolerance resistance.

Over Current Threshold Equation,

$$I_{TH}(Typ)[mA] = 19364 \times R_{LIM}[k\Omega]^{-0.98}$$
 $I_{TH} (Min)[mA] = 17500 \times R_{LIM}[k\Omega]^{-1} - 53$ 
 $I_{TH} (Max)[mA] = 22600 \times R_{LIM}[k\Omega]^{-1} + 104$ 

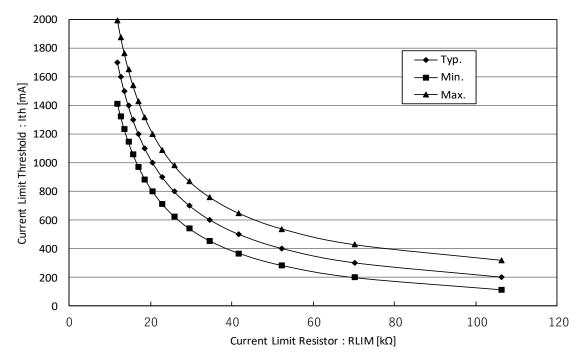


Figure 51. I<sub>TH</sub> vs. R<sub>LIM</sub>

D (kO)	Curre	nt Limit Threshold	(mA)
R <sub>LIM</sub> (kΩ)	MIN	TYP	MAX
106.30	111.7	200	316.6
70.28	196.0	300	425.5
52.40	281.0	400	535.2
41.73	366.4	500	645.5
34.65	452.1	600	756.2
29.60	538.2	700	867.4
25.83	624.5	800	978.8
22.91	711.0	900	1090.5
20.57	797.7	1000	1202.5
18.67	884.6	1100	1314.7
17.08	971.6	1200	1427.1
15.74	1058.8	1300	1539.8
14.59	1146.2	1400	1652.5
13.60	1233.6	1500	1765.5
12.73	1321.2	1600	1878.6
11.97	1408.9	1700	1991.9

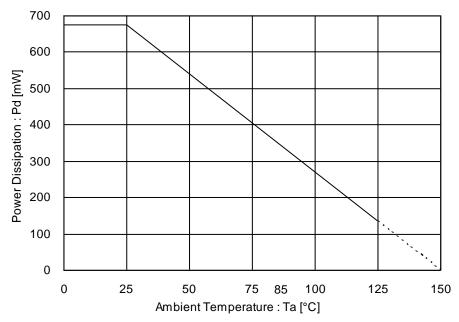
Table 1. I<sub>TH</sub> Tolerance vs. RLIM

# 7. Output Discharge Function

When the switch is turned off from disable control input or UVLO function, the  $60\Omega(Typ)$  output discharge circuit between OUT and GND turns on. By turning on this switch, electric charge at capacitive load is discharged. But when the voltage of IN declines extremely, then the OUT pin becomes high impedance without UVLO function.

# **Power Dissipation**

(SSOP6 package)



\* 70mm x 70mm x 1.6mm Glass Epoxy Board Figure 52. Power Dissipation Curve (Pd-Ta Curve)

# I/O Equivalence Circuit

Circuit								
Symbol	Pin No.	Equivalent Circuit						
EN	3	EN D						
/OC	4	/OC						
ILIM	5	ILIM D						
OUT	6	OUT						

### **Operational Notes**

### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

### 6. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

# 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

### **Operational Notes - continued**

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

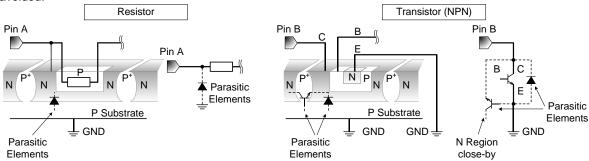


Figure 52. Example of monolithic IC structure

### 13. Ceramic Capacitor

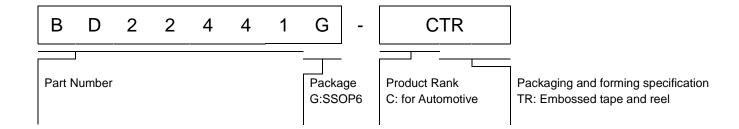
When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

# 14. Thermal Shutdown Circuit(TSD)

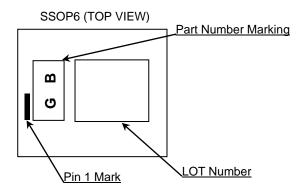
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

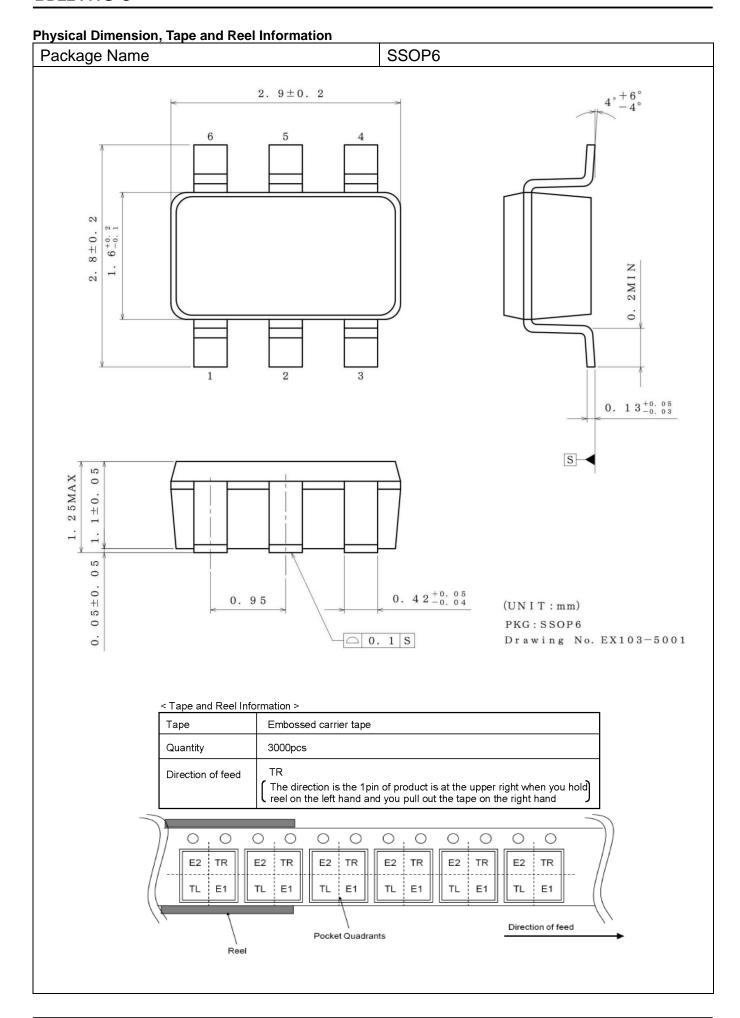
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

# **Ordering Information**



# **Marking Diagram**





# **Revision History**

Date	Revision	Changes	
26.Jun.2020	001	New Release	
26.Oct.2020	002	Change CGTR to CTR at Page 23 Packaging and forming specification.	

# **Notice**

### **Precaution on using ROHM Products**

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CL ACCIII	CLASS II b	СГУССШ
ſ	CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

### **Precaution for Foreign Exchange and Foreign Trade act**

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

#### Other Precaution

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

Notice-PAA-E Rev.004

### **General Precaution**

- 1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

Notice – WE Rev.001